October 1987 Revised July 2003

# SEMICONDUCTOR MM82C19

# 16-Line to 1-Line Multiplexer 3-STATE • 16-Line to 1-Line Multiplexer

#### **General Description**

FAIRCHILD

The MM74C150 and MM82C19 multiplex 16 digital lines to 1 output. A 4-bit address code determines the particular 1-of-16 inputs which is routed to the output. The data is inverted from input to output.

A strobe override places the output of MM74C150 in the logical "1" state and the output of MM82C19 in the high-impedance state.

All inputs are protected from damage due to static discharge by diode clamps to  $V_{CC}$  and GND.

### **Ordering Code:**

Order Number	Package Number	Package Description
MM74C150N	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-011, 0.600" Wide
MM82C19N	N24A	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-011, 0.600" Wide

**Features** 

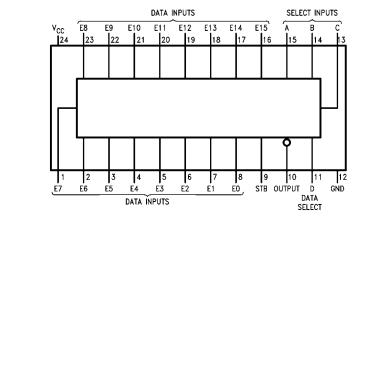
■ Wide supply voltage range: 3.0V to 15V

■ Guaranteed noise margin: 1.0V

■ High noise immunity: 0.45 V<sub>CC</sub> (typ.)

■ TTL compatibility: Drive 1 TTL Load

#### **Connection Diagram**

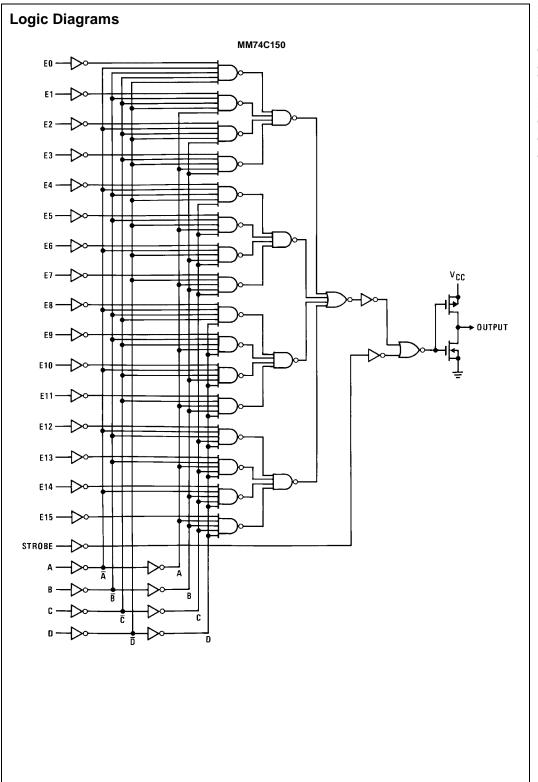


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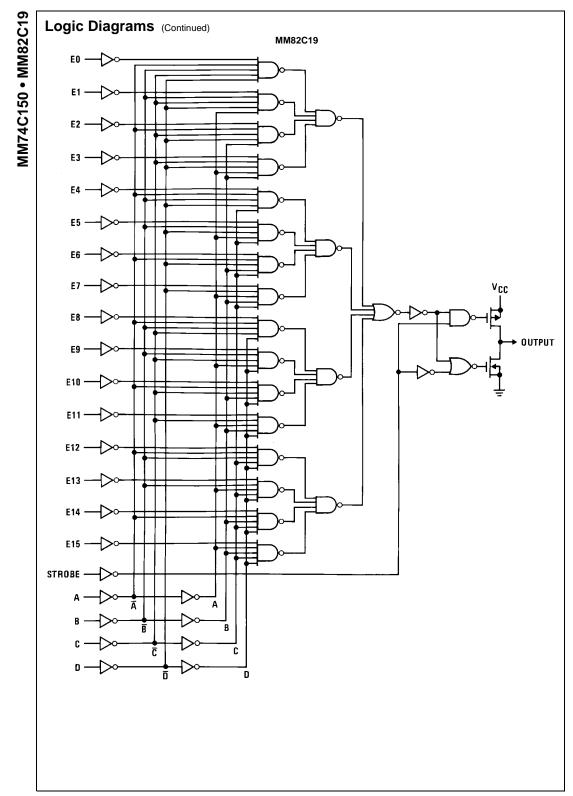
Г											nput	174C1	50									Outpu
F	D	С	в	Α	STROBE	E0	E1	E2	E3	E4	E5	E6	E7	E8	E9	E10	E11	E12	E13	E14	E15	W
-	Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1 (Note
	0	0	0	0	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1
	0	0	0	0	0	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0
	0	0	0	1	0	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1
	0	0	0	1	0	X	1	X	X	X	X	X	X	X	X	X	X	X	X	X	X	0
	0	0	1	0	0	X	X	0	X	X	X	X	X	X	X	X	X	X	X	X	X	1
	0 0	0 0	1 1	0 1	0 0	X X	X X	1 X	X 0	X X	0 1											
	0	0	1	1	0	x	x	X	1	X	x	x	x	x	x	X	X	x	x	X	X	0
	0	1	0	0	0	x	X	Х	x	0	X	X	x	X	X	X	X	Х	Х	Х	Х	1
	0	1	0	0	0	X	Х	Х	X	1	Х	X	X	Х	Х	X	Х	X	Х	Х	Х	0
	0	1	0	1	0	х	Х	Х	Х	Х	0	Х	Х	х	Х	х	Х	Х	Х	Х	Х	1
	0	1	0	1	0	х	Х	Х	Х	Х	1	Х	Х	Х	Х	х	Х	Х	Х	Х	Х	0
	0	1	1	0	0	Х	Х	х	Х	Х	Х	0	Х	Х	Х	Х	Х	х	Х	х	х	1
	0	1	1	0	0	Х	Х	Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	0
	0	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	Х	1
	0	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	Х	0
	1	0	0	0	0	Х	Х	Х	Х	Х	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	Х	1
	1	0	0	0	0	Х	Х	Х	Х	Х	Х	Х	Х	1	Х	Х	Х	Х	Х	Х	Х	0
	1	0	0	1	0	X	Х	Х	X	Х	X	Х	Х	Х	0	Х	Х	Х	Х	Х	Х	1
	1	0	0	1	0	X	X	X	X	X	X	X	X	X	1	X	X	X	X	X	X	0
	1 1	0 0	1 1	0 0	0 0	X X	0 1	X X	X X	X X	X X	X X	1 0									
	1	0	1	1	0	x	x	X	x	X	x	x	x	x	x	X	0	x	X	X	X	1
	1	0	1	1	0	x	X	Х	x	Х	X	x	x	X	X	X	1	Х	Х	Х	Х	0
	1	1	0	0	0	X	Х	Х	Х	Х	Х	X	X	Х	Х	Х	x	0	Х	Х	Х	1
	1	1	0	0	0	х	Х	х	Х	Х	Х	Х	Х	х	х	х	х	1	х	х	х	0
	1	1	0	1	0	х	Х	х	Х	Х	Х	х	Х	Х	Х	х	Х	х	0	х	х	1
	1	1	0	1	0	х	Х	Х	Х	Х	Х	Х	Х	Х	Х	х	Х	Х	1	Х	Х	0
	1	1	1	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0	Х	1
	1	1	1	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	Х	0
	1	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	0	1
	1	1	1	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	1	0

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#### Absolute Maximum Ratings(Note 2)

Voltage at Any Pin	–0.3V to $V_{CC}^{} + 0.3V$
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Power Dissipation	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V <sub>CC</sub> Range	3.0V to 15V
V <sub>CC</sub>	18V
Lead Temperature	
(soldering, 10 seconds)	260°C

**Note 2:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristic table provides conditions for actual device operation.

## **DC Electrical Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS to C	mos	ł	ļ			
V <sub>IN(1)</sub>	Logical "1" Input Voltage	$V_{CC} = 5.0V$	3.5			V
		$V_{CC} = 10V$	8.0			v
V <sub>IN(0)</sub>	Logical "0" Input Voltage	$V_{CC} = 5.0V$			1.5	
		$V_{CC} = 10V$			2.0	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} = -10 \ \mu A$	4.5			v
		$V_{CC} = 10V, I_{O} = -10 \ \mu A$	9.0			v
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_{O} = +10 \ \mu A$			0.5	v
		$V_{CC} = 10V, I_{O} = +10 \ \mu A$			1.0	v
IN(1)	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1.0	V
I <sub>IN(0)</sub>	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μΑ
loz	Output Current in High					
	Impedance State					
	MM82C19	$V_{CC} = 15V, V_{O} = 15V$		0.005	1.0	μA
		$V_{CC} = 15V, V_{O} = 0V$	-1.0	-0.005		
Icc	Supply Current	$V_{CC} = 15V$		0.05	300	μΑ
CMOS/LP1	TL Interface					
V <sub>IN(1)</sub>	Logical "1" Input Voltage	74C, 82C, V <sub>CC</sub> = 4.75V	V <sub>CC</sub> -1.5			V
VIN(0)	Logical "0" Input Voltage	74C, 82C, V <sub>CC</sub> = 4.75V			0.8	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	74C, 82C, $V_{CC} = 4.75V$ , $I_{O} = -1.6$ mA	2.4			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	74C, 82C, $V_{CC} = 4.75V$ , $I_{O} = 1.6$ mA			0.4	V
	ve (Short Circuit Current)		1			
SOURCE	Output Source Current	$V_{CC} = 5.0V$ , $V_{OUT} = 0V$ , $T_A = 25^{\circ}C$	-4.35	-8		mA
	(P-Channel)					
SOURCE	Output Source Current	$V_{CC} = 10V, V_{OUT} = 0V, T_A = 25^{\circ}C$	-20	-40		mA
	(P-Channel)					
SINK	Output Sink Current	$V_{CC} = 5.0V, V_{OUT} = V_{CC}, T_A = 25^{\circ}C$	4.35	8		mA
	(N-Channel)					
SINK	Output Sink Current	$V_{CC} = 10V, V_{OUT} = V_{CC}, T_A = 25^{\circ}C$	20	40		mA
	(N-Channel)					

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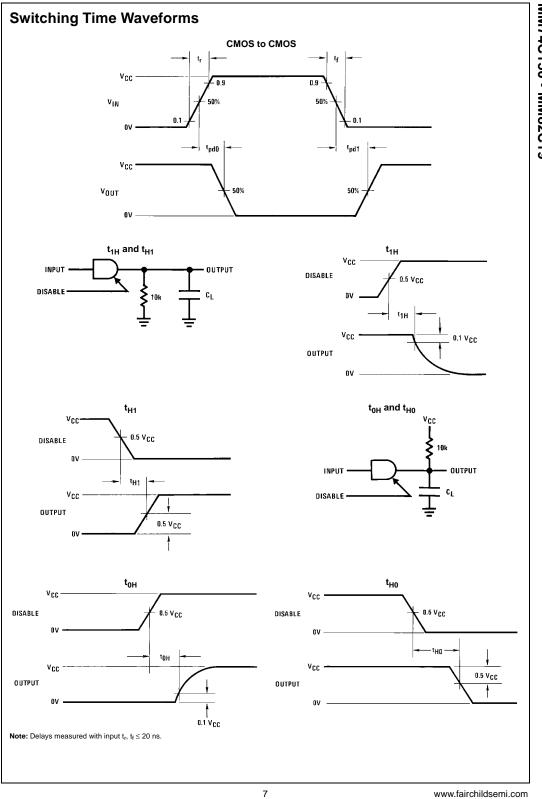
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Symbol	Parameter	Conditions	Min	Тур	Max	Uni
t <sub>pd0</sub> , t <sub>pd1</sub>	Propagation Delay Time to a	$V_{CC} = 5.0V$		250	600	
	Logical "0" or Logical "1"	$V_{CC} = 10V$		110	300	
	from Data Inputs to Output	$V_{CC} = 5.0V, C_{L} = 150 \text{ pF}$		290	650	n
		$V_{CC} = 10V, C_{L} = 150 \text{ pF}$		120	330	
t <sub>pd0</sub> , t <sub>pd1</sub>	Propagation Delay Time to a	$V_{CC} = 5.0V$		290	650	
	Logical "0" or Logical "1"	$V_{CC} = 10V$		120	330	n
	from Data Select Inputs to Output					
t <sub>pd0</sub> , t <sub>pd1</sub>	Propagation Delay Time to a	$V_{CC} = 5.0V$		120	300	
	Logical "0" or Logical "1"	$V_{CC} = 10V$		55	150	ns
	from Strobe to Output MM74C150					
t <sub>1H</sub> , t <sub>0H</sub>	Delay from Strobe to High	$V_{CC} = 5.0V, R_L = 10k, C_L = 5 pF$		80	200	
	Impedance State MM82C19	$V_{CC} = 10V, R_L = 10k, C_L = 5 \text{ pF}$		60	150	n
t <sub>H1</sub> , t <sub>H0</sub>	Delay from Strobe to Logical	$V_{CC} = 5.0V, R_L = 10k, C_L = 5 pF$		80	250	ns
	"1" Level or to Logical "0"	$V_{CC} = 10V, R_L = 10k, C_L = 5 \text{ pF}$		30	120	TR
	Level (from High Impedance State)					
	MM82C19					
CIN	Input Capacitance	Any Input (Note 4)		5.0		pl
C <sub>OUT</sub>	Output Capacitance	(Note 4)		11.0		pl
	MM82C19					
C <sub>PD</sub>	Power Dissipation Capacitance	(Note 5)		100		pF

Note 3: AC Parameters are guaranteed by DC correlated testing.

Note 4: Capacitance is guaranteed by periodic testing.

Note 5: C<sub>PD</sub> determines the no load AC power consumption of any CMOS device. For complete explanation, see Family Characteristics, application note AN-90.



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